

## General Description

The **VWA 0001148 AA** is a low noise amplifier MMIC operating in the frequency range 8 to 12GHz. The device is packaged in a 3x3 mm 16 lead Plastic Surface Mount Package (ROHS). This component uses VWA 5001134 AA VectraWave die.

The device has a linear gain of 19 dB and a typical noise figure of 1.0 dB. Typical operating supply current is only 30 mA with a supply voltage at +3 V. It is manufactured on a PHEMT Technology and is especially suited for radar and for telecommunication applications.

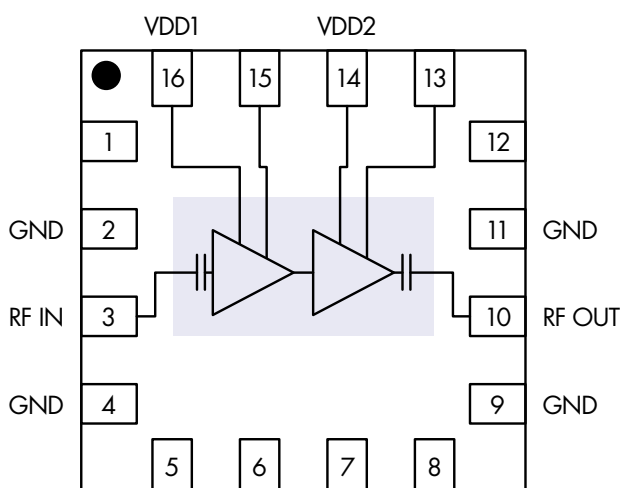
## Features

- Operating frequency range: 8 to 12GHz
- Gain: 19dB
- Noise figure: 1.0dB
- Gain Flatness: +/- 0.5dB
- Input Return Loss: -10dB typ.
- Output Return Loss: -12dB typ.
- Power supply: 30mA @ +3V
- Package: QFN 3 x 3mm 16 Lead

## Applications

- Radar
- Test and measurement
- Telecommunications

## Functional Block Diagram & Pins Assignment



Pin	Name	Pin	Name
1	NC	9	GND
2	GND	10	RF out
3	RF in	11	GND
4	GND	12	NC
5	NC	13	NC
6	NC	14	VDD2
7	NC	15	NC
8	NC	16	VDD1

### Electrical Specifications

Test conditions unless otherwise noted:

- $T_{amb} = +25^{\circ}C$
- ID = 30mA
- VDD = VDD1 = VDD2 = +3V
- Measurement reference plane: QFN accesses

Symbol	Parameter	Min	Typ	Max	Unit
F	Frequency range	8		12	GHz
G	Linear gain		19		dB
$\Delta G$	Small signal gain flatness		+/-0.5		dB
NF	Noise Figure		1.0		dB
OP1dB	Output power at 1dB compression		7		dBm
Psat	Saturated Output Power		9		dBm
S11	Input Return loss		-10		dB
S22	Output Return loss		-12		dB
VDD1_2	Operating supply voltage		+3		V
ID	Supply current		30		mA

### Absolute Maximum Ratings

Symbol	Maximum Ratings	Min	Max	Unit
VDD1_2	Drain voltage		+4	V
Pin	CW Input Power		+10	dBm
Tst	Storage temperature	-55	+125	$^{\circ}C$
Top	Operating temperature	-40	+85	$^{\circ}C$
Tch	Channel temperature		+150	$^{\circ}C$

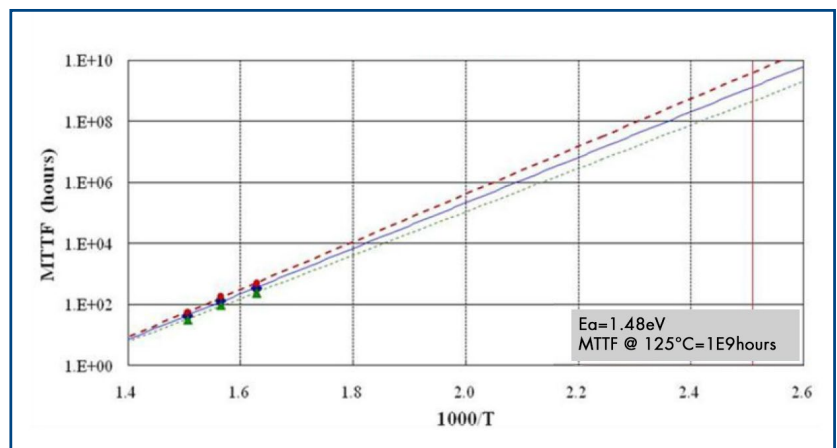
Operation of this device above any of these parameters may cause permanent damage.

### MTTF (Provided by Foundry)

The values shown here are calculated, only to be used as a guideline and represent reliability information under  $V_{ds}=+5V$  and drain current of 267mA/mm.

0.15 $\mu$ m Low noise pHEMT  
(PL15-10) / MTTF Test Arrhenius Plot

- ..... 10% failure line : MTTF @ 125C=4.7E8
- 50% failure line : MTTF @ 125C=1E9
- - - 90% failure line : MTTF @ 125C=4.1E9



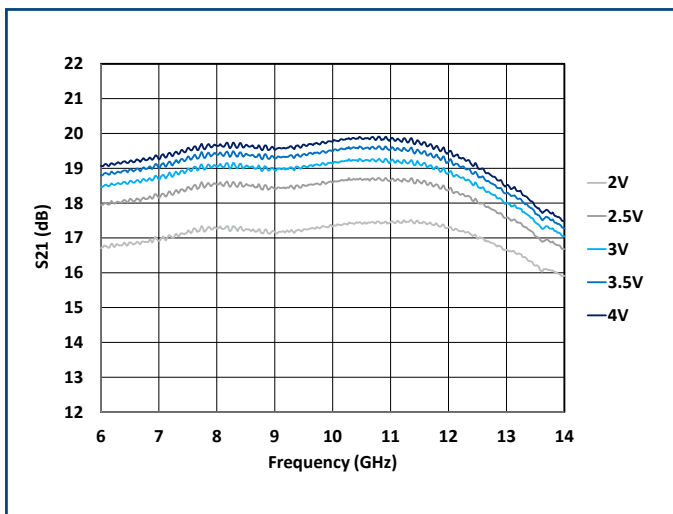
**Typical performances (Board measurements)**

**Measurement conditions otherwise noted:**

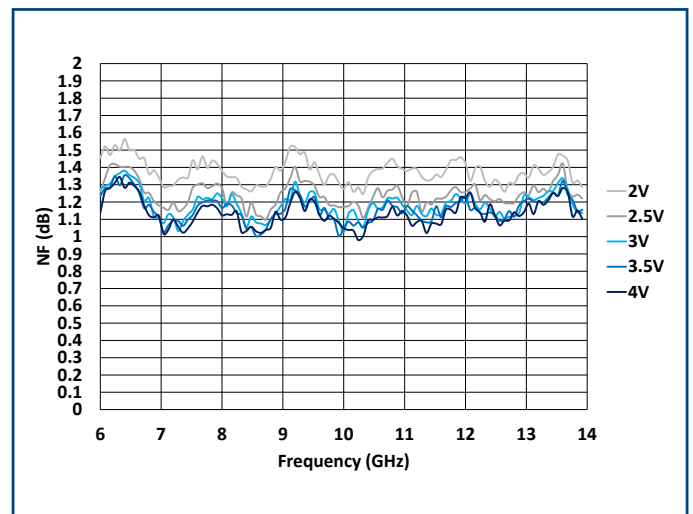
Measurement results reference plane at the QFN accesses.

- Tamb = +25°C
- VDD = VDD1 = VDD2 = +3V
- Typically, IDD = IDD1 + IDD2 = 30mA

**Small signal Gain (dB)**

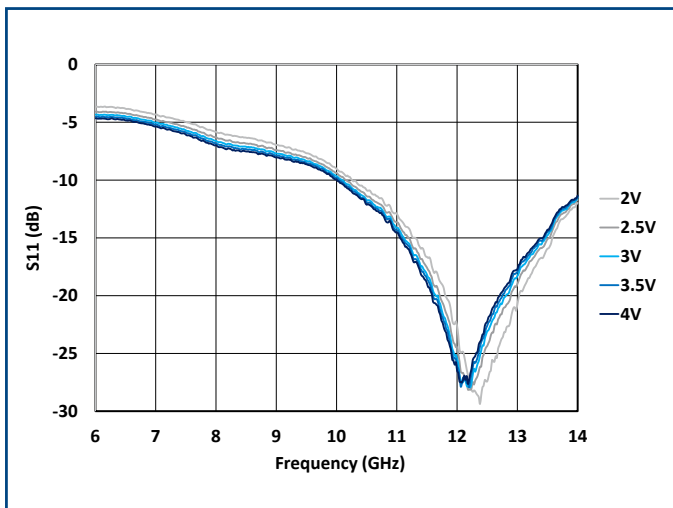


**Noise Figure (dB)\***

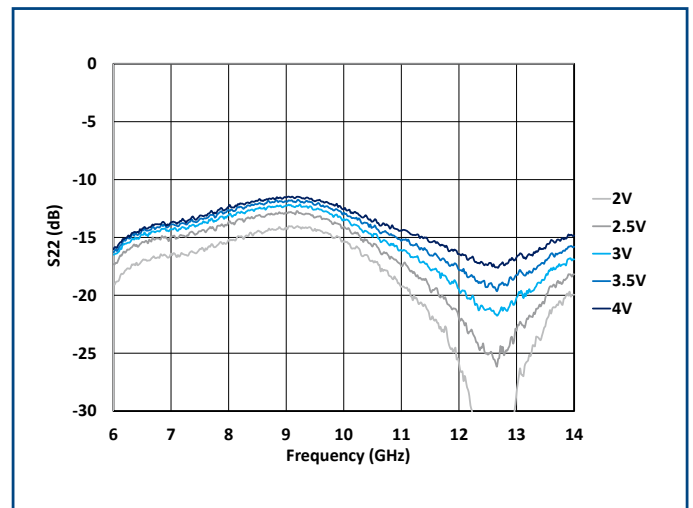


\*Setup measurement is given with accuracy of 0.2 dB.

**Input Return Loss (dB)**

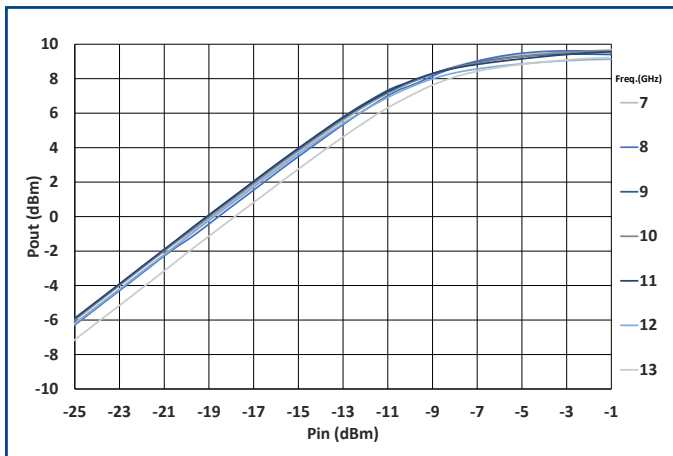


**Output Return Loss (dB)**

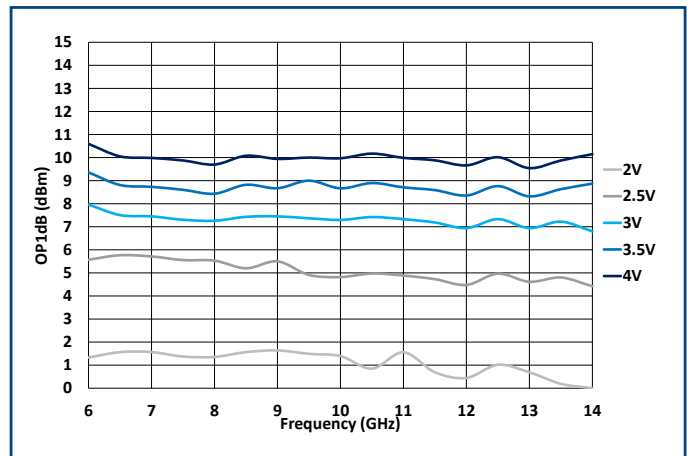


**Typical performances (Board measurements)**

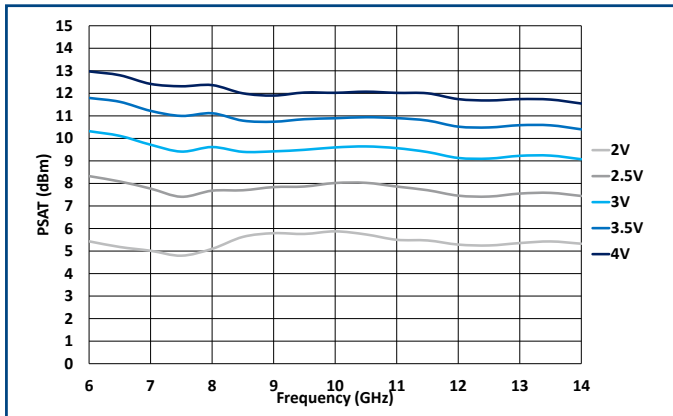
**Output power VS Input Power @ VDD=3V**



**P1dB vs Frequency**



**Psat vs Frequency**



**IDD vs VDD**

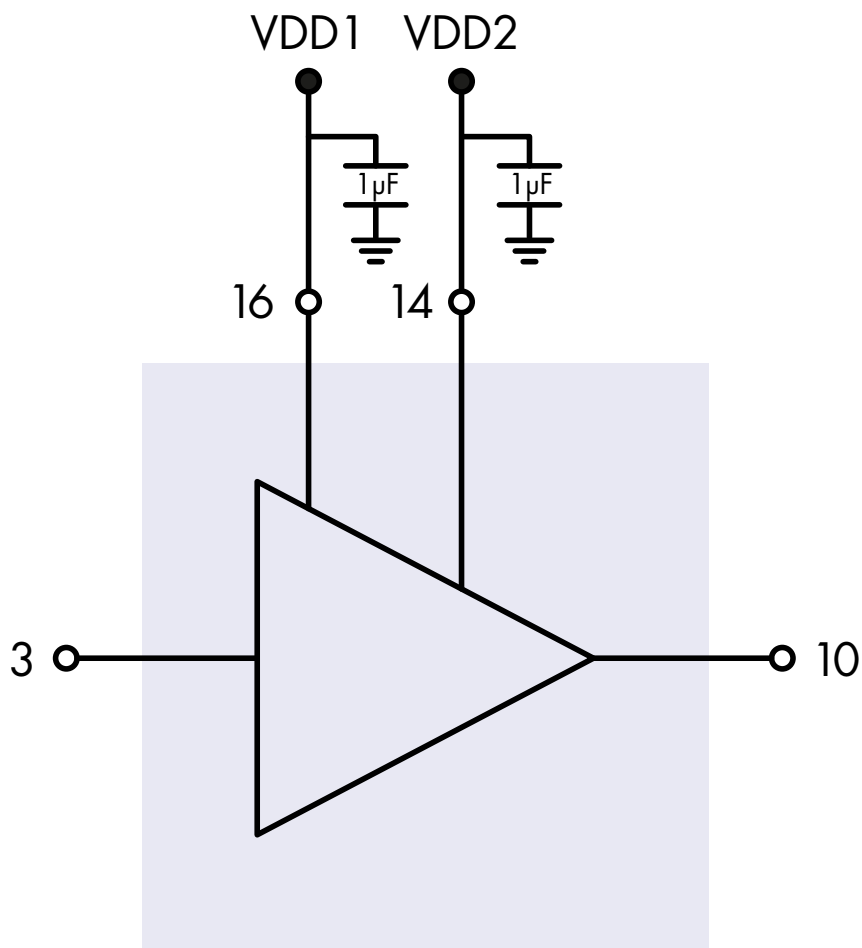
VDD (V)	IDD (mA)
2 V	23.5 mA
2.5 V	27 mA
3 V	30 mA
3.5 V	34 mA
4 V	38 mA

**Pin description**

Pin number	Name	Description	Electrical interface
3	RFin	AC coupled, amplifier input access. Internally matched 50 Ohms.	
10	RFout	AC coupled amplifier output access. Internally matched 50 Ohms.	
16, 14	VDD1, VDD2	1 <sup>st</sup> stage and 2 <sup>nd</sup> stage drain biasing access	
Exposed Pad	GND	Ground Pad must be connected to RF and DC Ground	

## Application circuit

- 1  $\mu\text{F}$  SMD Capacitors as close as possible to the QFN



## Biasing procedure

### Switch on

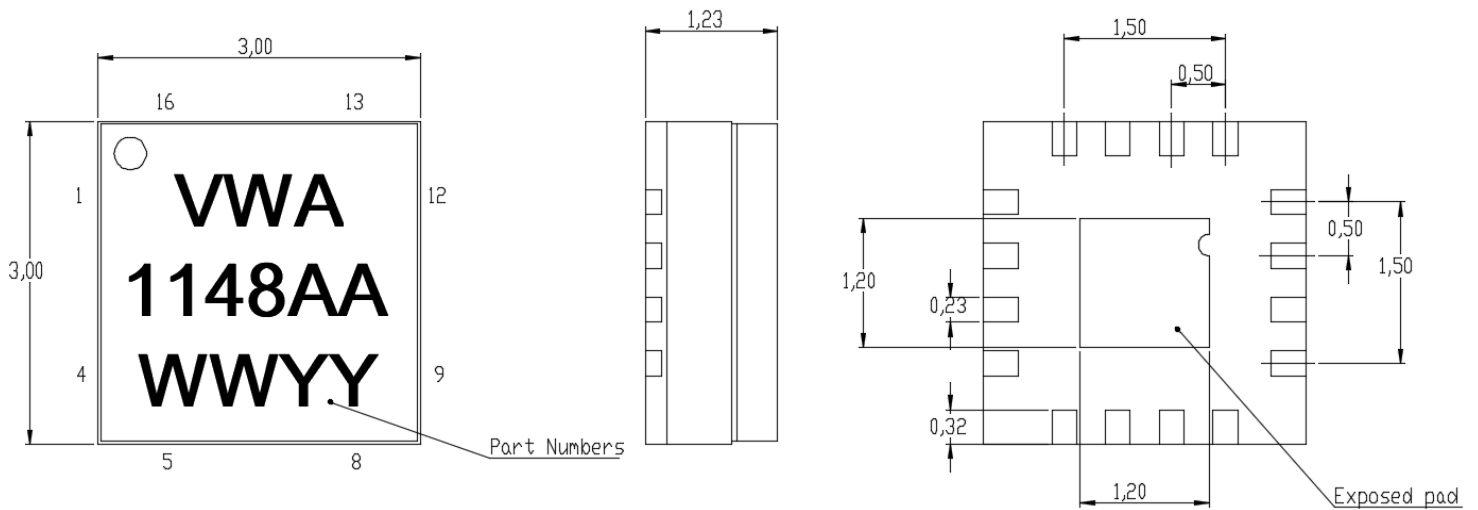
1. Set VDD1, VDD2 to +3V
2. Turn RFin ON

### Switch off

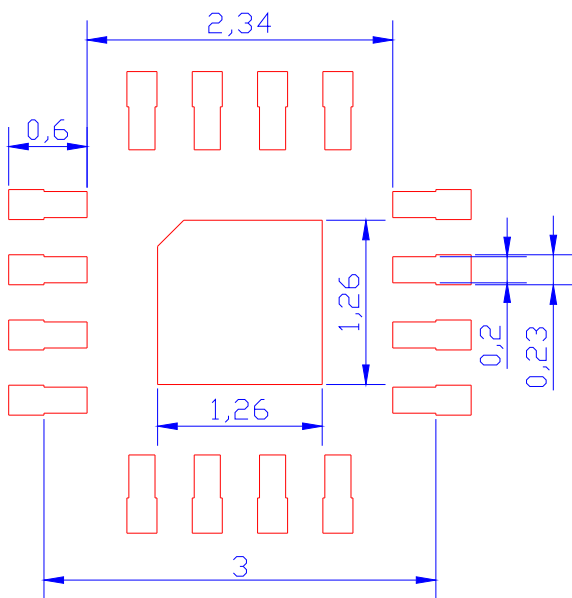
1. Turn RFin OFF
2. Decrease VDD1, VDD2 to 0V

## Mechanical Drawing

- QFN exposed PAD must be connected to ground (RF and DC)

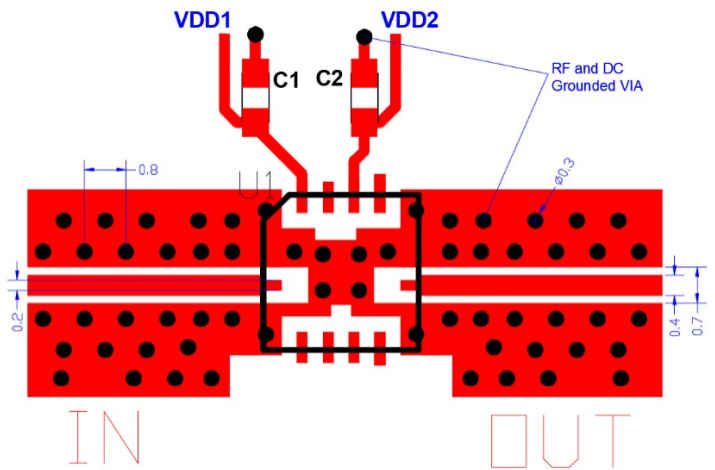


## Recommended Land pattern



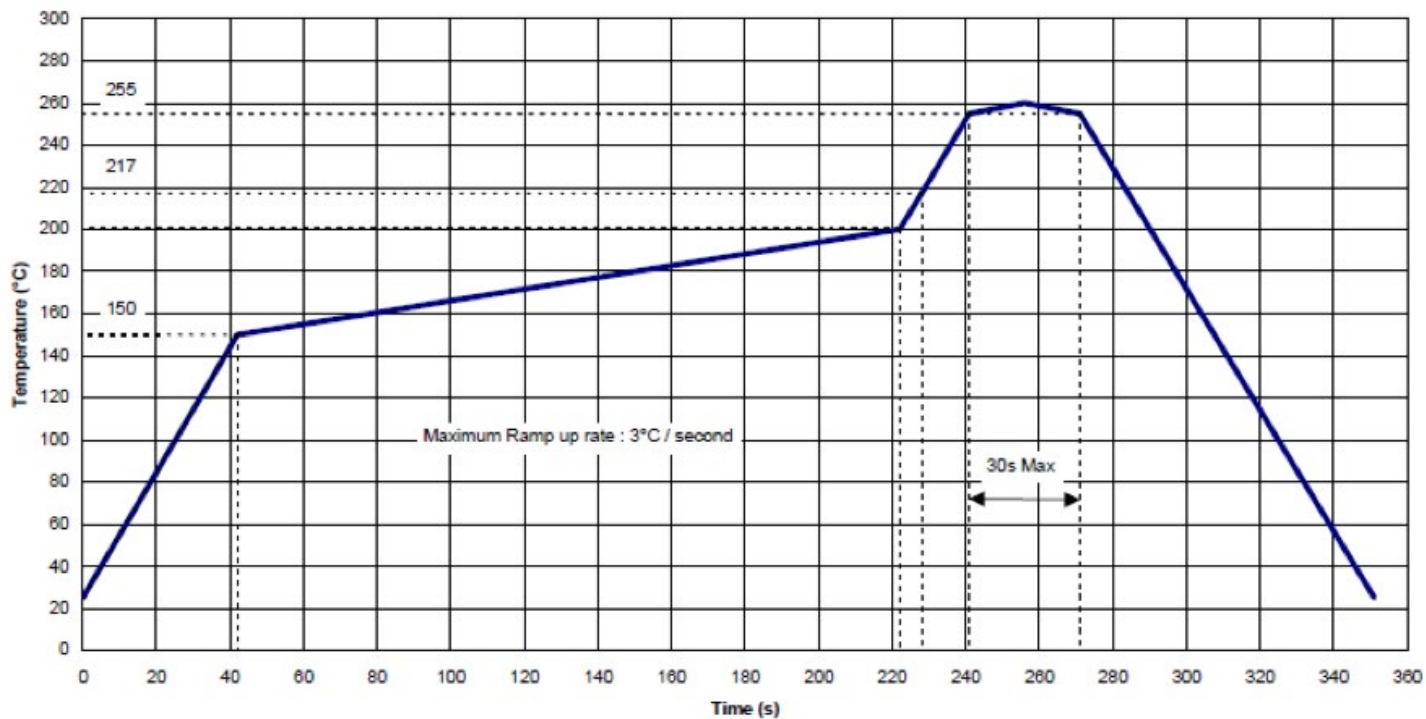
## Suggested Board Layout

- C1, C2: 0402 1  $\mu$ F/16V capacitor
- Substrate: RO4350B, thickness 0.254mm



## Soldering Recommendations

- Solder Stencil thickness : 127µm
- Solder : SAC 305 (ROHS)
- Temperature profile example : maximum recommended reflow profile (leadfree)



### Ordering Information

Product Code	Definition
VWA 0001148 AA	8 to 12GHz – 19dB – 1.0dB NF Low noise Amplifier

### Associated Material

Product Code	Definition
Packaged die Evaluation Board (packaged die EVB)	Contact factory
Mechanical files (DXF)	Contact factory
Measurements files (S2P)	Contact factory

### Product Compliance Information

#### Sensitivity Rating :

Test : Human Body Model (HBM)  
 Standard : JEDEC Standard JESD22-A114



**CAUTION ! ESD-Sensitive device**

#### RoHS-Compliance :

This part is compliant with EU 2011/65/ EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C15H12Br4O2) Free
- PFOS Free
- SVHC Free

### Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about Vectrawave:

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